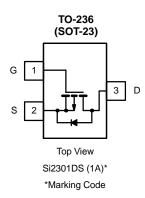
New Product

Vishay Siliconix

P-Channel 2.5-V (G-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(\Omega)$	I _D (A) ^b	
-20	0.130 @ V _{GS} = -4.5 V	-2.0	
	0.190 @ V _{GS} = -2.5 V	-1.6	



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	5 sec	Steady State	Unit
Drain-Source Voltage		V _{DS}	-20		.,
Gate-Source Voltage		V_{GS}	±8		_ V
O (' D ' O) (T 45000)b	T _A = 25°C	- I _D	-2.0	-1.75	
Continuous Drain Current (T _J = 150°C) ^b	T _A = 70°C		-1.6	-1.4	
Pulsed Drain Current ^a		I _{DM}	-10		A
Continuous Source Current (Diode Conduction) ^b		I _S	-0.75	-0.6	
D. Division b	T _A = 25°C	-	0.9	0.7	14/
Power Dissipation ^b	T _A = 70°C	P _D	0.57	0.45	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150		°C

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^b		115	140	0000
Maximum Junction-to-Ambient ^c	R _{thJA}	140	175	°C/W

 $For \ \ SPICE \ model \ information \ via \ the \ \ Worldwide \ \ Web: \ \ http://www.vishay.com/www/product/spice.htm$

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Parameter				Limits		Unit	
	Symbol	Test Conditions	Min	Тур	Max		
Static			•	•		•	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20				
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-0.45		-0.95	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μΑ	
	IDSS	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10		
On-State Drain Current ^a		$V_{DS} \le -5 \ V, V_{GS} = -4.5 \ V$	-6				
	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -2.5 \text{ V}$	-3			A	
Drain-Source On-Resistance ^a		$V_{GS} = -4.5 \text{ V}, I_D = -2.8 \text{ A}$		0.093	0.130	Ω	
	r _{DS(on)}	$V_{GS} = -2.5$ V, $I_D = -2.0$ A		0.140	0.190		
Forward Transconductance ^a	9fs	$V_{DS} = -5 \text{ V}, I_D = -2.8 \text{ A}$		6.5		S	
Diode Forward Voltage	V _{SD}	$I_S = -0.75 \text{ A}, V_{GS} = 0 \text{ V}$		-0.80	-1.2	V	
Dynamic ^b				•			
Total Gate Charge	Qg			4.2	10		
Gate-Source Charge	Q _{gs}	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}$ $I_D \cong -2.8 \text{ A}$		0.8		nC	
Gate-Drain Charge	Q _{gd}	. 5		0.8			
Input Capacitance	C _{iss}			500			
Output Capacitance	C _{oss}	$V_{DS} = -6 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		115		pF	
Reverse Transfer Capacitance	C _{rss}			62			
Switching ^c			•	•		•	
Turn-On Time	t _{d(on)}			6	25		
Turn-On Time	t _r	V_{DD} = -6 V, R_L = 6 Ω I_D \cong -1.0 A, V_{GEN} = -4.5 V		30	60	ns	
Turn-Off Time	t _{d(off)}	$R_G = 6 \Omega$		25	70	115	
	t _f			10	60		

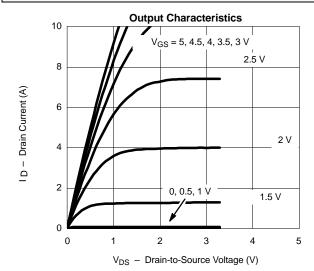
- Notes a. Pulse test: PW \leq 300 μ s duty cycle \leq 2%. b. For DESIGN AID ONLY, not subject to production testing. c. Switching time is essentially independent of operating temperature. FaxBack 408-970-5600



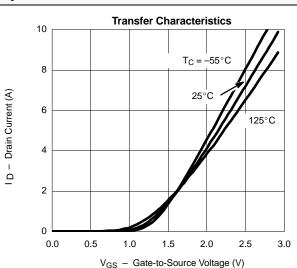
New Product

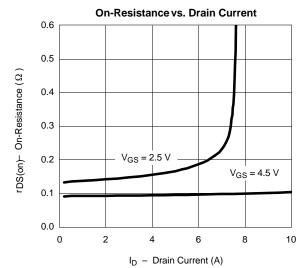
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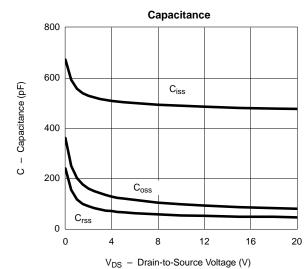
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

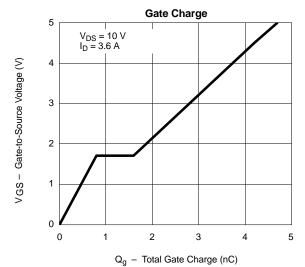


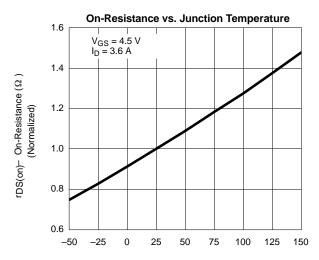










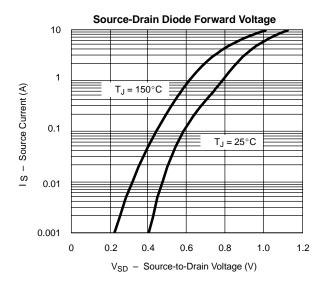


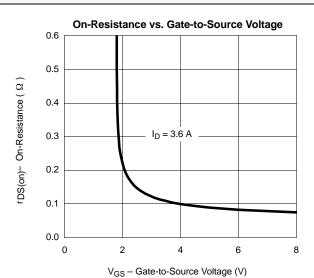
T_J – Junction Temperature (°C)

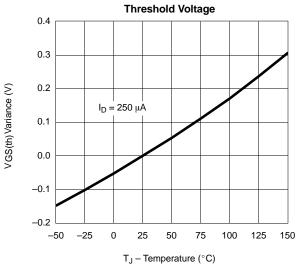
New Product

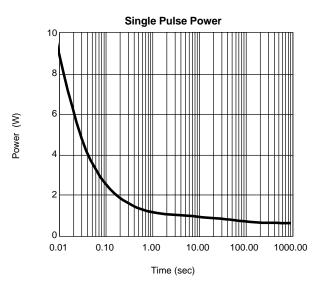


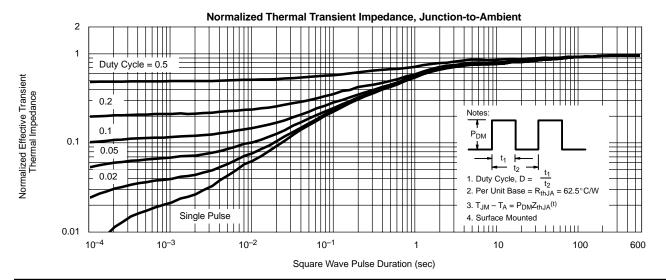
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)













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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com